

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35511 D

T-29-01

PRO ELECTRON SERIES (Bipolar—see page 5-37 for JFET)



Type No.	Case Style	V _{CE} [*] V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CS} [*] I _{CB0} (mA) Max	V _{CB} (V)	HFE h _{FE} 1 kHz Min	HFE h _{FE} 1 kHz Max	I _C & V _{CE} (mA) & (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC107	TO-18	50	45	6	15*	50	40	125	0.01 5 500* 2 5	0.6 0.2	0.55 0.7*	100	4.5	150	10		10	1	04
BC107A	TO-18	50	45	6	15*	50	40	125	0.01 5 500* 2 5	0.6 0.2	0.55 0.7*	100	4.5	150	10		10	1	04
BC107B	TO-18	50	45	6	15*	50	40	240	0.01 5 500* 2 5	0.6 0.2	0.55 0.7*	100	4.5	150	10		10	1	04
BC108	TO-18	30	20	5	15*	30	40	125	0.01 5 900* 2 5	0.6 0.2	0.55 0.7*	100	4.5	150	10		10	1	04
BC108A	TO-18	30	20	5	15*	30	40	125	0.01 5 260* 2 5	0.6 0.2	0.55 0.7*	100	4.5	150	10		10	1	04
BC108B	TO-18	30	20	5	15*	30	40	240	0.01 5 500* 2 5	0.6 0.2	0.55 0.7*	100	4.5	150	10		10	1	04
BC108C	TO-18	30	20	5	15*	30	40	450	0.01 5 900* 2 5	0.6 0.2	0.55 0.7*	100	4.5	150	10		10	1	04
BC109	TO-18	30	20	5	15*	30	100	240	0.01 5 900* 2 5	0.6 0.2	0.55 0.7*	100	4.5	150	10		4	1	04
BC109B	TO-18	30	20	5	15*	30	100	240	0.01 5 500* 2 5	0.6 0.2	0.55 0.7*	100	4.5	150	10		4	1	04
BC109C	TO-18	30	20	5	15*	30	100	450	0.01 5 900* 2 5	0.6 0.2	0.55 0.7*	100	4.5	150	10		4	1	04
BC140	TO-39	80*	40	7	100*	60	40	40	100 1 250 100* 1	1.0	1.8*	1A	25	50		850		2	14
BC140-6	TO-39	80*	40	7	100*	60	40	40	100 1 100 1	1.0	1.8*	1A	25	50		850		2	14
BC140-10	TO-39	80*	40	7	100*	60	63	160	100 1 100 1	1.0	1.8*	1A	25	50		850		2	14
BC140-16	TO-39	80*	40	7	100*	60	100	250	100 1 100 1	1.0	1.8*	1A	25	50		850		2	14
BC141	TO-39	100*	60	7	100*	60	40	250	100 1 100 1	1.0	1.8*	1A	25	50		850		2	14
BC141-6	TO-39	100*	60	7	100*	60	40	100	100 1 100 1	1.0	1.8*	1A	25	50		850		2	14
BC141-10	TO-39	100*	60	7	100*	60	63	160	100 1 100 1	1.0	1.8*	1A	25	50		850		2	14

6501130 NATL SEMICOND, (DISCRETE)

28C 35512

D



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} [*] (V) Min	V _{CE0} [*] (V) Max	V _{BE0} (V) Min	V _{BE0} (V) Max	I _{CB0} [*] (mA) Max	V _{CB} (V) Max	HFE		I _C & V _{CE}		V _{CE(SAT)} & V _{BE(ON)} [*]		I _C		C _{ob} (pF) Max	f _T		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.	
								Min	Max	Min	Max	Min	Max	Min	Max		Min	Max					Min
BC143	TO-5	60	60	5	40	50	40	20	200	2	1.5	1.5	500	200	20	60	50					63	
BC146-1	TO-92 (94)	20	20	4	40	50	40	80	200	2	1.5	1.5	500	200	20	60	50					04	
BC146-2	TO-92 (94)	20	20	4	40	50	40	140	350	2	1.5	1.5	500	200	20	60	50					04	
BC146-3	TO-92 (94)	20	20	4	40	50	40	280	550	2	1.5	1.5	500	200	20	60	50					04	
BC160	TO-39	40*	5	40	40	100	40	40	250	100	1.0	1.7*	1A	30	30	50	50	650				2	67
BC160-6	TO-39	40*	5	40	40	100	40	40	100	100	1.0	1.7*	1A	30	30	50	50	650				2	67
BC160-10	TO-39	40*	5	40	40	100	40	63	160	100	1.0	1.7*	1A	30	30	50	50	650				2	67
BC160-16	TO-39	40*	5	40	40	100	40	100	250	100	1.0	1.7*	1A	30	30	50	50	650				2	67
BC161	TO-39	60*	5	60	60	100	60	40	250	100	1.0	1.7*	1A	30	30	50	50	650				2	67
BC161-6	TO-39	60*	5	60	60	100	60	40	100	100	1.0	1.7*	1A	30	30	50	50	650				2	67
BC161-10	TO-39	60*	5	60	60	100	60	63	160	100	1.0	1.7*	1A	30	30	50	50	650				2	67
BC161-16	TO-39	60*	5	60	60	100	60	100	250	100	1.0	1.7*	1A	30	30	50	50	650				2	67
BC167	TO-92 (94)	60*	45	6	50	15*	50	110	500*	2	0.2	0.6	10	100	4.5	150	10				10	1	04
BC167A	TO-92 (94)	60*	45	6	50	15*	50	110	260*	2	0.2	0.6	10	100	4.5	150	10				10	1	04
BC167B	TO-92 (94)	60*	45	6	50	15*	50	110	500*	2	0.2	0.6	10	100	4.5	150	10				10	1	04
BC168	TO-92 (94)	60*	20	5	30	15*	30	110	900*	2	0.2	0.6	10	100	4.5	150	10				10	1	04
BC168A	TO-92 (94)	60*	20	5	30	15*	30	110	260*	2	0.2	0.6	10	100	4.5	150	10				10	1	04
BC168B	TO-92 (94)	60*	20	5	30	15*	30	110	500*	2	0.2	0.6	10	100	4.5	150	10				10	1	04

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TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 μA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35513 D

T-29-01

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} * V _{CB0} (V) Min	V _{CEO} (V) Min	V _{EB0} (V) Min	I _{CS} * I _{CB0} (mA) Max	H _{FE} h _{FE} 1 kHz* Min Max	I _C & V _{CE} (mA) & (V) Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)*} (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
												Min	Max				
BC168C	TO-92 (94)		20	5	15*	110 450	2 900*	5 5	0.2 0.6	10 100	4.5	150	10		1	04	
BC169	TO-92 (94)		20	5	15*	110 240	2 900*	5 5	0.2 0.6	10 100	4.5	150	4		1	04	
BC169B	TO-92 (94)		20	5	15*	110 240	2 500*	5 5	0.2 0.6	10 100	4.5	150	4		1	04	
BC169C	TO-92 (94)		20	5	15*	110 450	2 900*	5 5	0.2 0.6	10 100	4.5	150	4		1	04	
BC177	TO-18	50	45	5	100	110 125	2 500*	5 5	0.18	10 75*	4.5	150	10		1	71	
BC177A	TO-18	50	45	5	100	110 125	2 260*	5 5	0.18	10 75*	4.5	150	10		1	71	
BC177B	TO-18	50	45	5	100	110 240	2 500*	5 5	0.18	10 75*	4.5	150	10		1	71	
BC177VI	TO-18	50	45	5	100	110 75	2 150*	5 5	0.18	10 75*	4.5	150	10		1	71	
BC178	TO-18	30	25	5	100	110 125	2 900*	5 5	0.18	10 75*	4.5	150	10		1	71	
BC178A	TO-18	30	25	5	100	110 125	2 260*	5 5	0.18	10 75*	4.5	150	10		1	71	
BC178B	TO-18	30	25	5	100	110 240	2 500*	5 5	0.18	10 75*	4.5	150	10		1	71	
BC179	TO-18	25	20	5	100	110 125	2 900*	5 5	0.18	10 75*	4.5	150	4		1	71	
BC179A	TO-18	25	20	5	100	110 125	2 260*	5 5	0.18	10 75*	4.5	150	4		1	71	

6501130 NATL SEMICOND, (DISCRETE)

28C 35514

T-29-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB0} (V) Min	V _{BE0} (V) Min	I _{CB0} [*] (mA) Max	HFE h _{FE} 1 kHz Min	HFE h _{FE} 1 kHz Max	I _C & V _{CE} (mA) & (V) Min	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC179B	TO-18	25	5	100	110	240	2 5	0.18	0.75	10	4.5	150	10		4	1	71
BC182	TO-92 (97)	60	5	15	40	80	0.01 5	0.6	1.2	100	5	150	10		10	1	04
BC182A	TO-92 (97)	60	5	15	40	80	0.01 5	0.6	1.2	100	5	150	10		10	1	04
BC182B	TO-92 (97)	60	5	15	40	80	0.01 5	0.6	1.2	100	5	150	10		10	1	04
BC182L	TO-92 (94)	60	5	15	40	80	0.01 5	0.6	1.2	100	5	150	10		10	1	04
BC182LA	TO-92 (94)	60	5	15	40	80	0.01 5	0.6	1.2	100	5	150	10		10	1	04
BC182LB	TO-92 (94)	60	5	15	40	80	0.01 5	0.6	1.2	100	5	150	10		10	1	04
BC183	TO-92 (97)	45	5	15	40	80	0.01 5	0.6	1.2	100	5	150	10		10	1	04
BC183A	TO-92 (97)	45	5	15	40	80	0.01 5	0.6	1.2	100	5	150	10		10	1	04
BC183B	TO-92 (97)	45	5	15	40	80	0.01 5	0.6	1.2	100	5	150	10		10	1	04
BC183C	TO-92 (97)	45	5	15	40	80	0.01 5	0.6	1.2	100	5	150	10		10	1	04

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35515 D

Pro Electron Series

T-29-01

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} [*] V _{CB} (V) Max	V _{EB} (V) Min	V _{EB} (V) Max	IC _{ES} [*] IC _{BO} (mA) Max	V _{CB} (V)	HFE h _{FE} 1 kHz Min	HFE h _{FE} 1 kHz Max	IC @ V _{CE} (mA)	V _{CE} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Max	IC @ V _{BE} (mA)	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC183L	TO-92 (94)	30	45	5	15	30	30	40	125	0.01	0.6	1.2	100	5	150	10	1	04			
BC183LA	TO-92 (94)	30	45	5	15	30	30	40	80	0.01	0.6	1.2	100	5	150	10	1	04			
BC183LB	TO-92 (94)	30	45	5	15	30	30	40	125	0.01	0.6	1.2	100	5	150	10	1	04			
BC183LC	TO-92 (94)	30	45	5	15	30	30	40	240	0.01	0.6	1.2	100	5	150	10	1	04			
BC184	TO-92 (97)	30	45	5	15	30	30	80	450	0.01	0.6	1.2	100	5	150	10	1	04			
BC184B	TO-92 (97)	30	45	5	15	30	30	130	240	0.01	0.6	1.2	100	5	150	10	1	04			
BC184C	TO-92 (97)	30	45	50	15	30	30	100	450	0.01	0.6	1.2	100	5	150	10	1	04			
BC184L	TO-92 (94)	30	45	50	15	30	30	100	240	0.01	0.6	1.2	100	5	150	10	1	04			
BC184LB	TO-92 (94)	30	45	50	15	30	30	100	240	0.01	0.6	1.2	100	5	150	10	1	04			
BC184LC	TO-92 (94)	30	45	50	15	30	30	100	450	0.01	0.6	1.2	100	5	150	10	1	04			
BC204	TO-92 (92)	45	60	5	15	45	45	50	60	450	0.3	0.72*	10					10	1	71	
BC207	TO-92 (92)	45	60	5	15	40	40	110	450	2	0.25	0.6	100	6				10	1	04	
BC212	TO-92 (97)	50	60	5	15	30	30	60	400*	2	0.6	0.6	100	10	200	10	1	10	1	63	

6501130 NATL SEMICOND, (DISCRETE)

28C 35516

T-29-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} (V) Min	V _{EB} (V) Min	I _{CB} (mA) Max	HFE h _{FE} 1 kHz* Min	I _C & V _{CE} (mA) & (V) Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON)* (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC212A	TO-92 (97)	60	50	5	15	100	0.01 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC212B	TO-92 (97)	60	50	5	15	200	0.01 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC212L	TO-92 (94)	60	50	5	15	40 60 300 2	0.01 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC212LA	TO-92 (94)	60	50	5	15	40 60 300* 2	0.01 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC212LB	TO-92 (94)	60	50	5	15	40 60 400* 2	0.01 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC213	TO-92 (97)	45	30	5	15	40 60 80	0.01 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC213A	TO-92 (97)	45	30	5	15	40 60 300* 2	0.01 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC213B	TO-92 (97)	45	30	5	15	40 60 400* 2	0.01 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC213C	TO-92 (97)	45	30	5	15	350 600* 2	0.01 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC213L	TO-92 (94)	45	30	5	15	40 80 80*	0.01 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63
BC213LA	TO-92 (94)	45	30	5	15	40 80 300* 2	0.01 5	0.6 0.25	1.1 0.72*	100 10	10	200	10		10	1	63

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35517 D

T-29-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CB0} [*] (mA) Max	I _{CB0} (mA) Max	HFE h _{FE} 1 kHz [*] Min	HFE h _{FE} 1 kHz [*] Max	I _C & V _{CE} (mA) (V) Min	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC213LB	TO-92 (94)	45	30	5	15	30	40	80	0.01	0.6	1.1	100	10	200	10		10	1	63
							200	400*	2	0.25	0.6	0.72*	2						
BC213LC	TO-92 (94)	45	30	5	15	30	80	350	0.01	0.6	1.1	100	10	200	10		10	1	63
							80	600*	2	0.25	0.6	0.72*	2						
BC214	TO-92 (97)	45	30	5	15	30	40	80	0.01	0.6	1.1	100	10	200	10		2	1	63
							140	600*	2	0.25	0.6	0.72*	2						
BC214A	TO-92 (97)	45	30	5	15	30	40	80	0.01	0.6	1.1	100	10	200	10		2	1	63
							100	300*	2	0.25	0.6	0.72*	2						
BC214B	TO-92 (97)	45	30	5	15	30	40	80	0.01	0.6	1.1	100	10	200	10		2	1	63
							200	400*	2	0.25	0.6	0.72*	2						
BC214C	TO-92 (97)	45	30	5	15	30	40	80	0.01	0.6	1.1	100	10	200	10		2	1	63
							350	600*	2	0.25	0.6	0.72*	2						
BC214L	TO-92 (94)	45	30	5	15	30	100	140	0.01	0.6	1.1	100	10	200	10		2	1	63
							120	400	2	0.25	0.6	0.72*	2						
							140*	2	2	0.25	0.6	0.72*	2						
BC214LB	TO-92 (94)	45	30	5	15	30	100	140	0.01	0.6	1.1	100	10	200	10		2	1	63
							120	100	5	0.25	0.6	0.72*	2						
							200	400*	2	0.25	0.6	0.72*	2						
BC214LC	TO-92 (94)	45	30	5	15	30	100	140	0.01	0.6	1.1	100	10	200	10		2	1	63
							120	100	5	0.25	0.6	0.72*	2						
							350	600*	2	0.25	0.6	0.72*	2						
BC237-92	TO-92 (97)	50	45	6	50	20	100	140	0.01	0.25	0.77*	10	4.5				10	1	04
							120	2	5	0.6	0.6	100							
							125	500*	2	0.55	0.70*	2							
BC237A-92	TO-92 (97)	50	45	6	50	20	100	140	0.01	0.25	0.77*	10	4.5				10	1	04
							120	2	5	0.6	0.6	100							
							125	500*	2	0.55	0.70*	2							

6501130 NATL SEMICOND, (DISCRETE)

28C 35518
T-24-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} [*] (V) Min	V _{CE} [*] V _{CB} [*] (V) Max	V _{BE} [*] (V) Min	V _{BE} [*] (V) Max	I _{CE} [*] I _{CB} [*] (mA) Max	HFE h _{FE} 1 kHz Min	HFE h _{FE} 1 kHz Max	I _C & V _{CE} (mA) & (V) Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON) (V) Min	V _{BE} (SAT) & V _{BE} (ON) (V) Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC237B-92	TO-92 (97)	50	45	6	20	50	100	100	0.01 5	0.25	0.77*	0.6	10	4.5				10	1	04
BC238-92	TO-92 (97)	30	20	5	20	50	100	140	0.01 5	0.25	0.77*	0.6	100	4.5				10	1	04
BC238A-92	TO-92 (97)	30	20	5	20	50	120	140	0.01 5	0.25	0.77*	0.6	100	4.5				10	1	04
BC238B-92	TO-92 (97)	30	20	5	20	50	120	140	0.01 5	0.25	0.77*	0.6	100	4.5				10	1	04
BC238C-92	TO-92 (97)	30	20	5	20	50	240	450	0.01 5	0.25	0.77*	0.6	2	4.5				10	1	04
BC239-92	TO-92 (97)	30	20	5	20	50	100	140	0.01 5	0.25	0.77*	0.6	100	4.5				4	1	04
BC239B-92	TO-92 (97)	30	20	5	20	50	100	140	0.01 5	0.25	0.77*	0.6	100	4.5				4	1	04
BC239C-92	TO-92 (97)	30	20	5	20	50	450	900*	0.01 5	0.25	0.77*	0.6	2	4.5				4	1	04
BC261A	TO-18	45	45	50	45	50	100	140	0.01 5	0.25	0.9	0.6	100	4.5				6	3	71

TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 μA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35519 D

T-29-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} (V) Min	V _{EB} (V) Min	I _{CE} [*] I _{CB} (mA) Max	HFE h _{FE} 1 kHz Min	I _C & V _{CE} (mA) & (V) Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC261B	TO-18		45		50	100	0.01 5	0.25	0.9	10					6	3	71
BC262A	TO-18		20	5	50	100	0.01 5	0.25	0.9	10					6	3	71
BC262B	TO-18		20	5	50	100	0.01 5	0.25	0.9	10					6	3	71
BC263A	TO-18		20	5	50	100	0.01 5	0.25	0.9	10					2.5	3	71
BC263B	TO-18		20	5	50	100	0.01 5	0.25	0.9	10					2.5	3	71
BC307-92	TO-92 (97)	50	45	5	100	100	0.01 5	0.18	0.78	10					10	1	71
BC307A-92	TO-92 (97)	50	45	5	100	100	0.01 5	0.18	0.78	10					10	1	71
BC307B-92	TO-92 (97)	50	45	5	100	100	0.01 5	0.18	0.78	10					10	1	71
BC308-92	TO-92 (97)	30	25	5	100	100	0.01 5	0.18	0.78	10					10	1	71
BC308A-92	TO-92 (97)	30	25	5	100	100	0.01 5	0.18	0.78	10					10	1	71

6501130 NATL SEMICOND, (DISCRETE)

28C 35520

T-29-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	VCES* VCBO (V) Min	VCEO (V) Min	VEBO (V) Min	ICES* ICBO @ VCB (nA) Max	HFE hfe @ 1 kHz*		VCE(SAT) (V) Max		VBE(SAT) & VBE(ON)* (V) Min Max		IC (mA) Max	Cob (pF) Max	fT (MHz) Min Max	IC (mA) Max	toff (ns) Max	NF (dB) Max	Test Conditions	Process No.
						Min	Max	Min	Max	Min	Max								
BC308B-92	TO-92 (97)	30	25	5	100	100	0.01	5	0.18	0.78	10	10					1	71	
BC308C-92	TO-92 (97)	30	25	5	100	140	400	5	0.18	0.78	10	100					1	71	
BC309-92	TO-92 (97)	25	20	5	100	120	400	5	0.18	0.78	10	100					1	71	
BC309B-92	TO-92 (97)	25	20	5	100	120	400	5	0.18	0.78	10	100					1	71	
BC309C-92	TO-92 (97)	25	20	5	100	120	400	5	0.18	0.78	10	100					1	71	
BC317	TO-92 (92)	50	45	6	30	100	450	2	0.2	0.77*	10	100	4				1	04	
BC317A	TO-92 (92)	50	45	6	30	110	450	2	0.2	0.77*	10	100	4				1	04	
BC317B	TO-92 (92)	50	45	6	30	125	500*	2	0.2	0.77*	10	100	4				1	04	
BC318	TO-92 (92)	30	20	5	30	110	800	2	0.2	0.77*	10	100	4				1	04	
BC318A	TO-92 (92)	30	20	5	30	125	900*	2	0.2	0.77*	10	100	4				1	04	

TEST CONDITIONS:
 (1) IC = 200 μA, VCE = 5V, f = 1 kHz. (2) IC = 100 mA, VCC = 20V, IB¹ = IB² = 5 mA. (3) IC = 200 μA, VCE = 2V, f = 1 kHz. (4) IC = 100 mA, VCC = 10V, IB¹ = IB² = 10 mA. (5) IC = 10 mA, VCC = 3V, IB¹ = IB² = 1 mA. (6) IC = 100 μA, VCE = 5V, f = 1 kHz. (7) IC = 1 mA, VCE = 10V, f = 200 kHz. (8) IC = 1 mA, VCE = 5V, f = 1 kHz. (9) IC = 150 mA, VCC = 6V, IB¹ = IB² = 15 mA. (10) IC = 10 μA, VCE = 5V, f = WB.

Pro Electron Series

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6501130 NATL SEMICOND, (DISCRETE)

28C 35521 D

T-29-01

Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE0} [*] (V)		V _{BE0} (V)	I _{CS0} [*] (mA)		h _{FE} @ 1 kHz		I _C & V _{CE}		V _{CE(SAT)} (V)		V _{BE(SAT)} & V _{BE(ON)} [*] (V)		I _C (mA)	C _{ob} (pF)	f _T (MHz)		I _C (mA)	t _{off} (ns)	NF (dB)	Test Conditions	Process No.
		Min	Max		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max			Min	Max					
BC318B	TO-92 (92)	30	20	5	30	20	200	450	2	5	0.2	0.5	0.77*	10	100	4					6	1	04
BC318C	TO-92 (92)	30	20	5	30	20	100	450	0.01	5	0.2	0.5	0.77*	10	100	4					6	1	04
BC319	TO-92 (92)	30	20	5	30	20	40	200	0.01	5	0.2	0.5	0.77*	10	100	4					4	1	04
BC319B	TO-92 (92)	30	20	5	30	20	200	450	0.01	5	0.2	0.5	0.77*	10	100	4					4	1	04
BC319C	TO-92 (92)	30	20	5	30	20	100	420	0.01	5	0.2	0.5	0.77*	10	100	4					4	1	04
BC327	TO-92 (97)	50†	45	5	100†	45	40	100	300	1	0.7				500	4					4	1	67
BC327-10	TO-92 (97)	50†	45	5	100†	45	40	160	300	1	0.7				500	4					4	1	67
BC327-16	TO-92 (97)	50†	45	5	100†	45	40	250	300	1	0.7				500	4					4	1	67
BC327-25	TO-92 (97)	50†	45	5	100†	45	40	400	300	1	0.7				500	4					4	1	67
BC328	TO-92 (97)	30†	25	5	100†	25	40	600	100	1	0.7				500	4					4	1	67
BC328-10	TO-92 (97)	30†	25	5	100†	25	40	160	300	1	0.7				500	4					4	1	67
BC328-16	TO-92 (97)	30†	25	5	100†	25	40	250	300	1	0.7				500	4					4	1	67
BC328-25	TO-92 (97)	30†	25	5	100†	25	40	400	300	1	0.7				500	4					4	1	67
BC337	TO-92 (97)	50†	45	5	100†	45	40	600	100	1	0.7				500	4					4	1	14
BC337-10	TO-92 (97)	50†	45	5	100†	45	40	160	300	1	0.7				500	4					4	1	14
BC337-16	TO-92 (97)	50†	45	5	100†	45	40	250	300	1	0.7				500	4					4	1	14
BC337-25	TO-92 (97)	50†	45	5	100†	45	40	400	300	1	0.7				500	4					4	1	14

6501130 NATL SEMICOND, (DISCRETE)

28C 35522

T-29-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} [*] (V) Min	V _{CE0} [*] (V) Max	V _{EB0} [*] (V) Min	V _{EB0} [*] (V) Max	I _{CB0} [*] (mA) Max	V _{CB} (V)	H _{FE} h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) & (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min Max	I _C (mA)	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC338	TO-92 (97)	30†	25	5	100†	25	25	40 100	300 100	0.7	1.2*	500 300	4				4	1	14
BC338-10	TO-92 (97)	30†	25	5	100†	25	25	40 63	300 100	0.7	1.2*	500 300	4				4	1	14
BC338-16	TO-92 (97)	30†	25	5	100†	25	25	100 250	300 100	0.7	1.2*	500 300	4				4	1	14
BC338-25	TO-92 (97)	30†	25	5	100†	25	25	160 400	300 100	0.7	1.2*	500 300	4				4	1	14
BC415	TO-92 (97)	45	35	5	15	30	30	40 120	0.01 800	0.25 0.6	10 100						2	10	71
BC415A	TO-92 (97)	45	35	5	15	30	30	40 120	0.01 220	0.25 0.6	10 100						2	10	71
BC415B	TO-92 (97)	45	35	5	15	30	30	100 180	0.01 460	0.25 0.6	10 100						2	10	71
BC415C	TO-92 (97)	45	35	5	15	30	30	100 380	0.01 800	0.25 0.6	10 100						2	10	71
BC485	TO-92 (97)	45	45	5	100	30	30	15 40 60	1A 100 100	0.5 0.5	1.2 1.2*	500 300	4				4	1	14
BC485A	TO-92 (97)	45	45	5	100	30	30	15 40 100	1A 100 100	0.5 0.5	1.2 1.2*	500 300	4				4	1	14
BC485B	TO-92 (97)	45	45	5	100	30	30	15 40 160	1A 100 400	0.5 0.5	1.2 1.2*	500 300	4				4	1	14
BC485L	TO-92 (97)	45	45	5	100	30	30	15 40 60	1A 100 150	0.5 0.5	1.2 1.2*	500 300	4				4	1	14
BC547	TO-92 (97)	50	45	6	10	20	20	125	500* 2	0.25 0.6	0.77* 100	4.5					10	1	04
BC547A	TO-92 (97)	50	45	6	10	20	20	125	260* 2	0.25 0.6	0.77* 100	4.5					10	1	04

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CC} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CC} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CC} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35523 D

T-29-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	VCES* VCBO (V) Min	VCEO (V) Min	VEBO (V) Min	ICES* ICBO (mA) Max	HFE h _{FE} @ 1 kHz* Min	HFE h _{FE} @ 1 kHz* Max	VCE(SAT) (V) Max	VBE(SAT) & VBE(ON)* (V) Min	IC (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC547B	TO-92 (97)	50	45	6	10	240	500*	0.25 0.6	0.77* 0.55	10 100	4.5				10	1	04
BC547C	TO-92 (97)	50	45	6	10	450	900*	0.25 0.6	0.77* 0.55	10 100	4.5				10	1	04
BC548	TO-92 (97)	30	20	5	10	125	900*	0.25 0.6	0.77* 0.55	10 100	4.5				10	1	04
BC548A	TO-92 (97)	30	20	5	10	125	260*	0.25 0.6	0.77* 0.55	10 100	4.5				10	1	04
BC548B	TO-92 (97)	30	20	5	10	240	500*	0.25 0.6	0.77* 0.55	10 100	4.5				10	1	04
BC548C	TO-92 (97)	30	20	5	10	450	900*	0.25 0.6	0.77* 0.55	10 100	4.5				10	1	04
BC549	TO-92 (97)	30	20	5	10	240	900*	0.25 0.6	0.77* 0.55	10 100	4.5				4	1	04
BC549B	TO-92 (97)	30	20	5	10	240	900*	0.25 0.6	0.77* 0.55	10 100	4.5				4	1	04
BC549C	TO-92 (97)	30	20	5	10	240	500*	0.25 0.6	0.77* 0.55	10 100	4.5				4	1	04
BC550	TO-92 (97)	50	45	5	10	450	900*	0.25 0.6	0.77* 0.55	10 100					3	1	04
BC550B	TO-92 (97)	50	45	5	10	240	900*	0.25 0.6	0.77* 0.55	10 100					3	1	04
BC550C	TO-92 (97)	50	45	5	10	240	500*	0.25 0.6	0.77* 0.55	10 100					3	1	04
BC557	TO-92 (97)	50	45	5	100	75	260*	0.3 0.65	0.82* 0.6	10 100					10	1	71

6501130 NATL SEMICOND, (DISCRETE)

28C 35524

T-29-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} [*] (V) Min	V _{BO} (V) Min	I _{CB} [*] I _{BO} (mA) Max	H _{FE} h _{FE} 1 kHz Min Max	I _C & V _{CE} (mA) & (V) Max	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON) [*] (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC557A	TO-92 (97)	50	45	5	100	20	20	0.3 0.65	0.82* 0.75* 2	10 100					10	1	71
BC557B	TO-92 (97)	50	45	5	100	20	20	0.3 0.65	0.82* 0.6 0.75* 2	10 100					10	1	71
BC558	TO-92 (97)	30	25	5	100	20	20	0.3 0.65	0.82* 0.6 0.75 2	10 100					10	1	71
BC558A	TO-92 (97)	30	25	5	100	20	20	0.3 0.65	0.82* 0.6 0.75 2	10 100					10	1	71
BC558B	TO-92 (97)	30	25	5	100	20	20	0.3 0.65	0.82* 0.6 0.75 2	10 100					10	1	71
BC558C	TO-92 (97)	30	25	5	100	20	20	0.3 0.65	0.82* 0.6 0.75 2	10 100					10	1	71
BC559	TO-92 (97)	25	20	5	100	20	20	0.3 0.65	0.82* 0.6 0.75* 2	10 100					4	1	71
BC559A	TO-92 (97)	25	20	5	100	20	20	0.3 0.65	0.82* 0.6 0.75* 2	10 100					4	1	71
BC559B	TO-92 (97)	25	20	5	100	20	20	0.3 0.65	0.82* 0.6 0.75* 2	10 100					4	1	71
BC559C	TO-92 (97)	25	20	5	100	20	20	0.3 0.65	0.82* 0.6 0.75* 2	10 100					4	1	71
BC560	TO-92 (97)	50	45	5	100	45	45	0.3 0.65	0.82* 0.6 0.75* 2	10 100					2	1	71

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CC} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CC} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CC} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35525

D

T-29-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE(S)} V _{CB(S)} (V) Min	V _{CEO} (V) Min	V _{EBO} (V) Min	I _{CS} [*] I _{CB} (mA) Max	HFE h _{FE} 1 kHz Min Max	I _C @ (mA) Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	I _C @ (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C @ (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BC560A	TO-92 (97)	50	45	5	100	125 260*	2	0.3 0.65	0.82*	10					2	1	71
BC560B	TO-92 (97)	50	45	5	100	240 500*	2	0.3 0.65	0.6 0.75*	10					2	1	71
BC560C	TO-92 (97)	50	45	5	100	450 900*	2	0.3 0.65	0.6 0.75*	10					2	1	71
BCX58	TO-92 (97)		32	7	10	120 630 80 1000	2 5					125	10	800	6	3/4	04
BCX58-7	TO-92 (97)		32	7	10	120 220 80 100	2 5					125	10	800	6	3/4	04
BCX58-8	TO-92 (97)		32	7	10	20 180 40 310 120 400	5					125	10	800	6	3/4	04
BCX58-9	TO-92 (97)		32	7	10	40 250 60 460	5					125	10	800	6	3/4	04
BCX58-10	TO-92 (97)		32	7	10	60 380 100 630	5					125	10	800	6	3/4	04
BCX59	TO-92 (97)		45	7		120 630 80 1000	2 5	0.5	1.0	100		125	10	800		5	04
BCX59-7	TO-92 (97)		45	7		120 220 80 100	2 5	0.5	1.0	100		125	10	800		5	04
BCX59-8	TO-92 (97)		45	7		20 180 40 310 120 400	5	0.5	1.0	100		125	10	800		5	04
BCX59-9	TO-92 (97)		45	7		40 250 60 460 80 630	5 5 1	0.5	1.0	100		125	10	800		5	04

6501130 NATL SEMICOND, (DISCRETE)

28C 35526

D

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB0} (V) Min	V _{CE0} (V) Min	V _{EB0} (V) Min	I _{CB0} [*] (mA) Max	V _{CB} (V)	HFE h _{FE} 1 kHz [*] Min Max	I _C @ V _{CE} (mA) (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BCX59-10	TO-92 (97)		45	7			100 380 240 60	0.01 2 10 100	0.5	1.0	100		125	800		5	04
BCX78	TO-92 (97)		32	5			120 80 40	2 10 100	0.6	1.0	100						71
BCX78-7	TO-92 (97)		32	5			120 80 40	2 10 100	0.6	1.0	100						71
BCX78-8	TO-92 (97)		32	5			30 180 120 45	0.01 2 10 100	0.6	1.0	100						71
BCX78-9	TO-92 (97)		32	5			40 250 160 60	0.01 2 10 100	0.6	1.0	100						71
BCX78-10	TO-92 (97)		32	5			100 380 240 60	0.01 2 10 100	0.6	1.0	100						71
BCX79	TO-92 (97)		45	5			80 40 120	10 100 630	0.6	1.0	100						71
BCX79-7	TO-92 (97)		45	5			120 80	2 100	0.6	1.0	100						71
BCX79-8	TO-92 (97)		45	5			120 45 30 180	10 100 0.01 310	0.6	1.0	100						71
BCX79-9	TO-92 (97)		45	5			160 60 40 250	10 100 0.01 460	0.6	1.0	100						71

T-29-01

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CC} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CC} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CC} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35527 D

T-29-01

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} [*] VCBO (V) Min	V _{CE0} [*] (V) Min	V _{EB0} (V) Min	I _{CE} [*] I _{CB0} (mA) Max	HFE h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) & (V) Min Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min Max	I _C (mA) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BCX79-10	TO-92 (97)		45	5		240 60 100 380	1000 100 0.01 630	0.6	1.0	100							71
BCY56	TO-18		45	5	100	40 100 125 40	10 450 500* 0.01	0.6	0.7*	2					5	1	04
BCY57	TO-18	25	20	5	100	200 200 240 100	10 800 900* 0.01		0.6	0.7*					5	1	04
BCY58	TO-18		32	7	10 [†]	40 80 125	100 1000 700*	0.35 0.7	0.6 0.85 0.7*	10 100 2	6	125	10	800	6	4/1	04
BCY58-7	TO-18		32	7	10 [†]	40 80 125	100 1000 250*	0.35 0.7	0.6 0.85 0.7*	10 100 2	6	125	10	800	6	4/1	04
BCY58-8	TO-18		32	7	10 [†]	40 80 175	100 1000 350*	0.35 0.7	0.6 0.85 0.7*	10 100 2	6	125	10	800	6	4/1	04
BCY58-9	TO-18		32	7	10 [†]	40 80 250	100 1000 500*	0.35 0.7	0.6 0.85 0.7*	10 100 2	6	125	10	800	6	4/1	04
BCY58-10	TO-18		32	7	10 [†]	40 80 350	100 1000 700*	0.35 0.7	0.6 0.85 0.7*	10 100 2	6	125	10	800	6	4/1	04
BCY59	TO-18		45	7	10 [†]	40 80 125	100 1000 700*	0.35 0.7	0.6 0.85 0.7*	10 100 2	6	125	10	800	6	4/1	04
BCY59-7	TO-18		45	7	10 [†]	40 80 125	100 1000 250*	0.35 0.7	0.6 0.85 0.7*	10 100 2	6	125	10	800	6	4/1	04
BCY59-8	TO-18		45	7	10 [†]	40 80 175	100 1000 350*	0.35 0.7	0.6 0.85 0.7*	10 100 2	6	125	10	800	6	4/1	04
BCY59-9	TO-18		45	7	10 [†]	40 80 250	100 1000 500*	0.35 0.7	0.6 0.85 0.7*	10 100 2	6	125	10	800	6	4/1	04

6501130 NATL SEMICOND, (DISCRETE)

28C 35528

7-33-01



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} *		V _{CEO} (V) Min	V _{BE0} (V) Min	I _{CS} * I _{CS0} (nA) Max	h _{FE} 1 kHz*		I _C & V _{CE} (V)	V _{CE(SAT)} & V _{BE(ON)} * (V)		C _{ob} (pF) Max	f _T (MHz)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
		Min	Max				Min	Max		Min	Max		Min	Max				
BCY59-10	TO-18	45	10†	45	7	100	40	1000	1	0.35	0.6	6	125	10	800	6	4/1	04
BCY70	TO-18	40	10	40	5	0.1	40	700*	1	0.7	0.75	6	250	10	420	6	5/6	71
BCY71	TO-18	45	500	45	5	0.01	40	1	1	0.25	0.6	6	200	10	420	2	6	71
BCY71A	TO-18	45	500	45	5	0.1	80	1	1	0.25	0.6	6	300	10	420	2	6	71
BCY72	TO-18	25	500	25	5	10	80	1	1	0.25	0.6	6	200	10	420	6	5/6	71
BD135	TO-126	45	100	45	5	500	25	500	2	0.5	1.0*	6	50	50	420	6	5/6	37
BD135-6	TO-126	45	100	45	5	150	40	250	2	0.5	1.2	6	50	50	420	6	5/6	37
BD135-10	TO-126	45	100	45	5	150	40	100	2	0.5	1.2	6	50	50	420	6	5/6	37
BD135-16	TO-126	45	100	45	5	150	40	150	2	0.5	1.2	6	50	50	420	6	5/6	37
BD136	TO-126	45	100	45	5	150	40	150	2	0.5	1.2	6	50	50	420	6	5/6	37
BD136-6	TO-126	45	100	45	5	150	40	150	2	0.5	1.2	6	50	50	420	6	5/6	37
BD136-10	TO-126	45	100	45	5	150	40	150	2	0.5	1.2	6	50	50	420	6	5/6	37
BD136-16	TO-126	45	100	45	5	150	40	150	2	0.5	1.2	6	50	50	420	6	5/6	37
BD137	TO-126	60	100	60	5	150	40	150	2	0.5	1.2	6	50	50	420	6	5/6	38

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35529 D

T-33-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE(S)} V _{CE(S)} (V) Min	V _{CEO} (V) Min	V _{BE(O)} (V) Min	I _{CS} [*] I _{CS(O)} @ (nA) Max	H _{FE} h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) (V) 2	V _{CE(SAT)} (V) Max	V _{BE(ON)} [*] (V) Min	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD137-6	TO-126	60	60	5	100	40 100	150 2	0.5		500		50				38
BD137-10	TO-126	60	60	5	100	63 160	150 2	0.5		500		50				38
BD138	TO-126	60	60	5	100	40 160	150 2	0.5		500		50				78
BD138-6	TO-126	60	60	5	100	40 100	150 2	0.5		500		50				78
BD138-10	TO-126	60	60	5	100	63 160	150 2	0.5		500		50				78
BD139	TO-126	80	80	5	100	25 500	500 2	0.5	1.0*	500		50	420	6	5/6	39
BD139-6	TO-126	80	80	5	100	40 160	500 2	0.5	1.0*	500		50				39
BD139-10	TO-126	80	80	5	100	25 500	500 2	0.5	1.0*	500		50				39
BD140	TO-126	80	80	5	100	40 160	500 2	0.5	1.0*	500		50	420	6	5/6	79
BD157	TO-126		250		100 μA	30 240	50 10									36
BD158	TO-126		300		100 μA	30 240	50 10									36
BD159	TO-126		350		100 μA	30 240	50 10									36
BD185	TO-126		30		100 μA	40 500	2 2A	1.0	1.2*	2A						4F
BD186	TO-126		30		100 μA	40 500	2 2A	1.0	1.5*	2A						5F
BD187	TO-126		45		100 μA	40 500	2 2A	1.0	1.5*	2A						4F
BD188	TO-126		45		100 μA	40 500	2 2A	1.0	1.5*	2A						5F
BD189	TO-126		60		100 μA	40 500	2 2A	1.0	1.5*	2A						4F
BD190	TO-126		60		100 μA	40 500	2 2A	1.0	1.5*	2A						5F
BD201	TO-220	60	45	5	10 μA	30 3A	2 2A	1.0	1.5*	3A		3	300	6	5/6	4A
BD202	TO-220	60	45	5	10 μA	30 3A	2 2A	1.0	1.5*	3A		3	300	6	5/6	5A

6501130 NATL SEMICOND, (DISCRETE)

28C 35530

F-33-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] VCBO (V)		V _{BE} O (V)	I _{CS} [*] ICBO (nA)	h _{FE} @ I _C & V _{CE} (V)		V _{CE(SAT)} & V _{BE(ON)} [*] (V)		C _{ob} (pF)	f _T (MHz)		t _{off} (ns)	NF (dB)	Test Conditions	Process No.
		Min	Max			Min	Max	Min	Max		Min	Max				
BD203	TO-220	60	60	5		30	2	2	1.0		3					4A
BD204	TO-220	60	60	5	10 μA	30	2A	2	1.0							5A
BD220	TO-220					30	120	500	1.0							4F
BD221	TO-220					30	120	1A	1.0							4F
BD222	TO-220					20	80	1.5A	1.0							4F
BD223	TO-220					30	120	300	1.0							5F
BD224	TO-220					30	120	1A	1.0							5F
BD225	TO-220					20	80	1.5A	1.0							5F
BD233	TO-126	45	45		100 μA	25	1A	2	0.6		3	250	420	6	5/6	4F
BD234	TO-126	45	45		100 μA	25	1A	2	0.6		3	250	420	6	5/6	5F
BD235	TO-126	60	60		100 μA	25	1A	2	0.6		3	250	420	6	5/6	4F
BD236	TO-126	60	60		100 μA	25	1A	2	0.6		3	250	420	6	5/6	5F
BD237	TO-126	80	80		100 μA	25	1A	2	0.6		3	250	420	6	5/6	4F
BD238	TO-126	80	80		100 μA	25	1A	2	0.6		3	250	420	6	5/6	5F
BD239	TO-220	45	45		200 μA	15	1A	4	0.7		3	200	420	6	5/6	4F
BD239A	TO-220	60	60		200 μA	15	1A	4	0.7		3	200	420	6	5/6	4F
BD239B	TO-220	80	80		200 μA	15	1A	4	0.7		3	200	420	6	5/6	4F
BD239C	TO-220	100	100		200 μA	15	1A	4	0.7		3	200	420	6	5/6	4F
BD240	TO-220	45	45		200 μA	15	1A	4	0.7		3	200	420	6	5/6	5F
BD240A	TO-220	80	80		200 μA	15	1A	4	0.7		3	200	420	6	5/6	5F

TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_C² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 5V, f = 1 mA, V_{CE} = 5V, I_B¹ = I_B² = 15 mA. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35531 D

7-33-01

Pro Electron Series

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*]		V _{EB}	I _{CS} [*]		HFE		I _C & V _{CE}	V _{BE(SAT)} & V _{BE(ON)} [*]		C _{ob}	f _T		I _C	t _{off}	NF	Test Conditions	Process No.
		V _{CE0}	V _{CEB}		I _{CS0}	V _{CB}	h _{FE}	h _{FE}		Min	Max		Min	Max					
BD240B	TO-220	80	80		200 μA*	80	15	40	1A 4	0.7	1.3*	1A	3	200	420	6	5/6	5F	
BD240C	TO-220	100	100		200 μA*	100	15	40	1A 4	0.7	1.3*	1A	3	200	420	6	5/6	5F	
BD241	TO-220	80	45		200 μA*	45	10	25	3A 4	1.3	1.8*	3A	3	500	420	6	5/6	4F	
BD241A	TO-220	80	60		200 μA*	60	10	25	3A 4	1.3	1.8*	3A	3	500	420	6	5/6	4F	
BD241B	TO-220	80	80		200 μA*	80	10	25	3A 4	1.3	1.8*	3A	3	500	420	6	5/6	4F	
BD241C	TO-220	80	100		200 μA*	100	10	25	3A 4	1.3	1.8*	3A	3	500	420	6	5/6	4F	
BD242	TO-220	80	45		200 μA*	45	10	25	3A 4	1.2	1.8*	3A	3	500	420	6	5/6	5E	
BD242A	TO-220	80	60		200 μA*	60	10	25	3A 4	1.2	1.8*	3A	3	500	420	6	5/6	5E	
BD242B	TO-220	80	80		200 μA*	80	10	25	3A 4	1.2	1.8*	3A	3	500	420	6	5/6	5E	
BD242C	TO-220	80	100		200 μA*	100	10	25	3A 4	1.2	1.8*	3A	3	500	420	6	5/6	5E	
BD243	TO-220		45		400 μA*	45	30	15	300 4				3	500				4A	
BD243A	TO-220		60		400 μA*	60	30	15	300 4				3	500				4A	
BD243B	TO-220		80		400 μA*	80	30	15	300 4				3	500				4A	
BD243C	TO-220		100		400 μA*	100	30	15	300 4				3	500				4A	
BD244	TO-220		45		400 μA*	45	30	15	300 4				3	500				4A	
BD244A	TO-220		60		400 μA*	60	30	15	300 4				3	500				5A	
BD244B	TO-220		80		400 μA*	80	30	15	300 4				3	500				5A	
BD244C	TO-220		100		400 μA*	100	30	15	300 4				3	500				5A	
BD344	TO-126	60	60	5	500	60	60	40	50 200	0.4		200	50	50				78	

6501130 NATL SEMICOND, (DISCRETE)

28C 35532

D

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} [*] (V)		V _{CE0} [*] (V)		V _{BE0} (V)		I _{CB0} (mA)		I _{CB0} (mA)		I _C & V _{CE}		V _{CE(SAT)} & V _{BE(ON)} [*] (V)		C _{ob} (pF)		f _T (MHz)		t _{off} (ns)		NF (dB) Max	Test Conditions	Process No.	
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max				
BD345	TO-126	60	60	5	500	60	60	50	1	40	250	200	1	0.4	200	20	50	50							38
BD346	TO-220	60			10 μA	60	60	140	2A	2.5	4A	2.5			200	4	250								5A
BD347	TO-220	60			10 μA	60	60	140	2A	2.5	4A	2.5			200	4	250								4A
BD348	TO-126	80	80	5	500	80	80	100	1	50	250	250	1	0.5	250	17	50	50							79
BD349	TO-126	80	80		500	80	80	100	1	50	250	250	1	0.5	1.5* 250	15	50	50							39
BD370A	TO-237 (91)	45	45		100	45	45	25	500	2	400	100	1	0.7	1.2* 1A	30	50	200				420	6	5/6	78
BD370A-10	TO-237 (91)	80	80		100	45	45	25	500	2	400	100	1	0.7	1.2* 1A	30	50	200				420	6	5/6	78
BD370A-16	TO-237 (91)	80	80		100	45	45	25	500	2	400	100	1	0.7	1.2* 1A	30	50	200				420	6	5/6	78
BD370A-25	TO-237 (91)	80	80		100	45	45	25	500	2	400	100	1	0.7	1.2* 1A	30	50	200				420	6	5/6	78
BD370B	TO-237 (91)	80	80		100	60	60	40	400	1	400	100	1	0.7	1.2* 1A	30	50	200				420	6	5/6	78
BD370B-10	TO-237 (91)	80	80		100	60	60	40	400	1	400	100	1	0.7	1.2* 1A	30	50	200				420	6	5/6	78
BD370B-16	TO-237 (91)	80	80		100	60	60	40	400	1	400	100	1	0.7	1.2* 1A	30	50	200				420	6	5/6	78
BD370B-25	TO-237 (91)	80	80		100	60	60	40	400	1	400	100	1	0.7	1.2* 1A	30	50	200				420	6	5/6	78
BD370C	TO-237 (91)	80	80		100	80	80	40	400	1	400	100	1	0.7	1.2* 1A	30	50	200				420	6	5/6	78
BD370C-6	TO-237 (91)	80	80		100	80	80	40	400	1	400	100	1	0.7	1.2* 1A	30	50	200				420	6	5/6	78
BD370C-10	TO-237 (91)	80	80		100	80	80	40	400	1	400	100	1	0.7	1.2* 1A	30	50	200				420	6	5/6	78
BD370C-16	TO-237 (91)	80	80		100	80	80	40	400	1	400	100	1	0.7	1.2* 1A	30	50	200				420	6	5/6	78

T-33-01

TEST CONDITIONS: (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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6501130 NATL SEMICOND, (DISCRETE)

28C 35533 D

T-33-01

Pro Electron Series

PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE0} [*] (V) Min	V _{CE0} [*] (V) Max	V _{BE0} (V) Min	I _{CE0} [*] (mA) Max	V _{CB} (V)	HFE		I _C & V _{CE}		V _{CE(SAT)} & V _{BE(ON)} [*]		C _{cb} (pF) Max	f _T		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.	
							Min	Max	Min	Max	Min	Max		Min	Max					Min
BD370D	TO-237 (91)	100	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	79
BD370D-6	TO-237 (91)	100	80	25	500	500	2	25	500	2	1	0.7	1.2*	30	50	200	420	6	5/6	79
BD370D-10	TO-237 (91)	100	80	25	500	500	2	25	500	2	1	0.7	1.2*	30	50	200	420	6	5/6	79
BD371A	TO-237 (91)	45	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371A-10	TO-237 (91)	45	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371A-16	TO-237 (91)	45	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371A-25	TO-237 (91)	45	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371B	TO-237 (91)	60	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371B-10	TO-237 (91)	60	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371B-16	TO-237 (91)	60	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371B-25	TO-237 (91)	60	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371C	TO-237 (91)	80	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371C-6	TO-237 (91)	80	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371C-10	TO-237 (91)	80	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371C-16	TO-237 (91)	80	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	38
BD371D	TO-237 (91)	100	100	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	39
BD371D-6	TO-327 (91)	100	100	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	39
BD371D-10	TO-237 (91)	100	100	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	39
BD372A	TO-237 (90)	45	80	25	400	500	2	25	400	100	1	0.7	1.2*	30	50	200	420	6	5/6	78

6501130 NATL SEMICOND, (DISCRETE)

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PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} * V _{CSO} (V) Min	V _{CEO} (V) Min	V _{EBO} (V) Min	I _{CS} * I _{CSO} (mA) Max	V _{CB} (V) Max	HFE h _{FE} @ 1 kHz*		I _C & V _{CE} (mA) (V) Max	V _{CE(SAT)} & V _{BE(ON)} * (V) (V) Max Min		I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) @ I _C (mA) Min Max		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
							Min	Max		Min	Max			Min	Max				
BD372A-10	TO-237 (90)	80	45		100	45	25 63	500 160	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372A-16	TO-237 (90)	80	45		100	45	25 100	500 250	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372A-25	TO-237 (90)	80	45		100	45	25 160	500 400	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372B	TO-237 (90)	80	60		100	60	25 40	500 400	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372B-10	TO-237 (90)	80	60		100	60	25 63	500 160	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372B-16	TO-237 (90)	80	60		100	60	25 100	500 250	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372B-25	TO-237 (90)	80	60		100	60	25 160	500 400	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372C	TO-237 (90)	80	80		100	80	25 40	500 400	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372C-6	TO-237 (90)	80	80		100	80	25 40	500 100	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372C-10	TO-237 (90)	80	80		100	80	25 63	500 160	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372C-16	TO-237 (90)	80	100		100	100	25 100	500 250	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	78
BD372D	TO-237 (90)	80	100		100	100	25 40	500 400	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	79
BD372D-6	TO-237 (90)	80	100		100	100	25 40	500 100	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	79
BD372D-10	TO-237 (90)	80	100		100	100	25 63	500 160	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	79
BD373A	TO-237 (90)	80	45		100	45	25 40	500 400	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373A-10	TO-237 (90)	80	45		100	45	25 63	500 160	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38
BD373A-16	TO-237 (90)	80	45		100	45	25 100	500 250	2 1	0.7	1.2*	1A	30	50	200	420	6	5/6	38

TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CC} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CC} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CC} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CC} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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6501130 NATL SEMICOND, (DISCRETE)

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Pro Electron Series

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} [*] V _{BO} (V) Min	I _{CE} [*] I _{BO} (mA) Max	V _{CE} @ V _{CB} (V)	HFE h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) (V)	V _{CE} (SAT) (V) Max	V _{BE} (SAT) & V _{BE} (ON) [*] (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	f _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD373A-25	TO-237 (90)	80	45	100	45	25 160	500 2 400 1	0.7	1.2 [*]	1A	30	50	420	6	5/6	38
BD373B	TO-237 (90)	80	80	100	80	25 40	500 2 400 1	0.7	1.2 [*]	1A	30	50	420	6	5/6	38
BD373B-10	TO-237 (90)	80	80	100	80	25 63	500 2 160 1	0.7	1.2 [*]	1A	30	50	420	6	5/8	38
BD373B-16	TO-237 (90)	80	60	100	60	25 100	500 2 250 1	0.7	1.2 [*]	1A	30	50	420	6	5/8	38
BD373B-25	TO-237 (90)	80	60	100	60	25 160	500 2 400 1	0.7	1.2 [*]	1A	30	50	420	6	5/6	38
BD373C	TO-237 (90)	80	80	100	80	25 40	500 2 400 1	0.7	1.2 [*]	1A	30	50	420	6	5/6	38
BD373C-6	TO-237 (90)	80	80	100	80	25 40	500 2 100 1	0.7	1.2 [*]	1A	30	50	420	6	5/6	38
BD373C-10	TO-237 (90)	80	80	100	80	25 63	500 2 160 1	0.7	1.2 [*]	1A	30	50	420	6	5/6	38
BD373C-16	TO-237 (90)	80	80	100	80	25 100	500 2 250 1	0.7	1.2 [*]	1A	30	50	420	6	5/6	38
BD373D	TO-237 (90)	80	100	100	100	25 40	500 2 400 1	0.7	1.2 [*]	1A	30	50	420	6	5/6	39
BD373D-6	TO-237 (90)	80	100	100	100	25 40	500 2 100 1	0.7	1.2 [*]	1A	30	50	420	6	5/6	39
BD373D-10	TO-237 (90)	80	100	100	100	25 63	500 2 160 1	0.7	1.2 [*]	1A	30	50	420	6	5/6	39
BD375	TO-126	50	45	2 μA	45	20 40	1A 2 375 2	1.0	1.5 [*]	1A	30	50	420	6	5/6	38
BD375-6	TO-126	50	45	2 μA	45	20 40	1A 2 150 2	1.0	1.5 [*]	1A	30	50	420	6	5/6	38
BD375-10	TO-126	50	45	2 μA	45	20 63	1A 2 160 2	1.0	1.5 [*]	1A	30	50	420	6	5/6	38
BD375-16	TO-126	50	45	2 μA	45	20 100	1A 2 250 2	1.0	1.5 [*]	1A	30	50	420	6	5/6	38
BD375-25	TO-126	50	45	2 μA	45	20 150	1A 2 375 2	1.0	1.5 [*]	1A	30	50	420	6	5/6	78
BD376	TO-126	50	45	2 μA	45	20 40	1A 2 150 2	1.0	1.5 [*]	1A	30	50	420	6	5/6	78
BD376-6	TO-126	50	45	2 μA	45	20 40	1A 2 100 2	1.0	1.5 [*]	1A	30	50	420	6	5/6	78

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6501130 NATL SEMICOND, (DISCRETE)

28C 35536

D

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE} [*] (V) Min	V _{CE0} (V) Min	V _{ES0} (V) Min	I _{CS} [*] I _{CB0} (mA) Max	HFE h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) & (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min Max	I _C (mA) Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD376-10	TO-126	50	45		2 μA	20 160 63	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD376-16	TO-126	50	45		2 μA	100 200 63	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD376-25	TO-126	50	45		2 μA	20 375 150	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD377	TO-126	75	60		2 μA	40 375 150	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD377-6	TO-126	75	60		2 μA	40 100 150	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD377-10	TO-126	75	60		2 μA	20 160 63	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD377-16	TO-126	75	60		2 μA	20 250 150	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD377-25	TO-126	75	60		2 μA	150 375 150	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	38
BD378	TO-126	75	60		2 μA	40 375 150	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD378-6	TO-126	75	60		2 μA	20 100 150	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD378-10	TO-126	75	60		2 μA	20 160 63	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD378-16	TO-126	75	60		2 μA	20 250 150	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD378-25	TO-126	75	60		2 μA	150 375 150	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	78
BD379	TO-126	100	80		2 μA	20 375 150	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	39
BD379-6	TO-126	100	80		2 μA	40 100 150	1A 2 150 2	1.0	1.5*	1A	30	50	200	420	6	5/6	39

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TEST CONDITIONS: (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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6501130 NATL SEMICOND, (DISCRETE)

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Pro Electron Series

Type No.	Case Style	V _{CE0} [*] (V) Min	V _{CE0} [*] (V) Max	V _{CB0} [*] (V) Min	V _{CB0} [*] (V) Max	I _{CB0} [*] (mA) Min	I _{CB0} [*] (mA) Max	h _{FE} 1 kHz [*] Min	h _{FE} 1 kHz [*] Max	I _C & V _{CE} (mA) & (V) Min	I _C & V _{CE} (mA) & (V) Max	V _{CE(SAT)} & V _{BE(ON)} [*] (V) & (V)		I _C @ (mA)		C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
												Min	Max	Min	Max								
BD379-10	TO-126	80	100	80	80	2 μA	80	20	63	1A	2	1.0	1.5*	1A	2	30	50	200	420	5/6	39		
BD379-16	TO-126	80	100	80	80	2 μA	80	100	250	1A	2	1.0	1.5*	1A	2	30	50	200	420	5/6	39		
BD379-25	TO-126	80	100	80	80	2 μA	80	150	375	1A	2	1.0	1.5*	1A	2	30	50	200	420	5/6	39		
BD380	TO-126	80	100	80	80	2 μA	80	40	375	1A	2	1.0	1.5*	1A	2	30	50	200	420	5/6	79		
BD380-6	TO-126	80	100	80	80	2 μA	80	40	100	1A	2	1.0	1.5*	1A	2	30	50	200	420	5/6	79		
BD380-10	TO-126	80	100	80	80	2 μA	80	63	160	1A	2	1.0	1.5*	1A	2	30	50	200	420	5/6	79		
BD380-16	TO-126	80	100	80	80	2 μA	80	100	250	1A	2	1.0	1.5*	1A	2	30	50	200	420	5/6	79		
BD380-25	TO-126	80	100	80	80	2 μA	80	150	375	1A	2	1.0	1.5*	1A	2	30	50	200	420	5/6	79		
BD433	TO-126	22	22	5	22	100 μA	22	50	85	2A	1	0.5	1.1*	2A	1		3	250	420	5/6	4E		
BD434	TO-126	22	22	5	22	100 μA	22	50	475	500	1	0.5	1.1*	2A	1	30	3	250	420	5/6	5E		
BD435	TO-126	32	32	5	32	100 μA	32	50	475	500	1	0.5	1.1*	2A	1	30	3	250	420	5/6	4E		
BD436	TO-126	32	32	5	32	100 μA	32	50	475	500	1	0.5	1.1*	2A	1	30	3	250	420	5/6	5E		
BD437	TO-126	45	45	5	45	100 μA	45	40	236	2A	1	0.6	1.2*	2A	1	30	3	250	420	5/6	4E		
BD438	TO-126	45	45	5	45	100 μA	45	40	236	500	1	0.6	1.2*	2A	1	30	3	250	420	5/6	5E		
BD439	TO-126	60	60	5	60	100 μA	60	25	236	2A	1	0.8	1.5*	2A	1	30	3	250	420	5/6	4E		

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6501130 NATL SEMICOND, (DISCRETE)

28C 35538

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PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} (V)		V _{CE0} (V)		V _{CB} (V)		h _{FE} (1 kHz)		I _C & V _{CE} (V)		V _{CE(SAT)} & V _{BE(ON)} (V)		I _C (mA)		f _T (MHz)		t _{off} (ns)		NF (dB)		Test Conditions	Process No.
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max		
BD440	TO-126	60†	60	5	100 μA	60	25 40 20	2A 500 10	1 5	0.8	1.5*	2A	3	250	3	420	6	5/6	5E				
BD441	TO-126	80†	80	5	100 μA	80	15 40 15	2A 500 10	1 5	0.8	1.5*	2A	3	250	3	420	6	5/6	4E				
BD442	TO-126	80†	80	5	100 μA	80	15 40 15	2A 500 10	1 5	0.8	1.5*	2A	3	250	3	420	6	5/6	5E				
BD533	TO-220	80†	45	5	100 μA	45	25 40 20	2A 500 10	2 5	0.8	1.5*	2A	3	250	3	420	6	5/6	4E				
BD534	TO-220	80†	45	5	100 μA	45	25 40 20	2A 500 10	2 5	0.8	1.5*	2A	3	250	3	420	6	5/6	5E				
BD535	TO-220	80†	60	5	100 μA	60	25 40 20	2A 500 10	2 5	0.8	1.5*	2A	3	250	3	420	6	5/6	4E				
BD536	TO-220	80†	60	5	100 μA	60	25 40 20	2A 500 10	2 5	0.8	1.5*	2A	3	250	3	420	6	5/6	5E				
BD537	TO-220	80†	80	5	100 μA	80	15 40 15	2A 500 10	2 5	0.8	1.5*	2A	3	250	3	420	6	5/6	4E				
BD538	TO-220	80†	80	5	100 μA	80	15 40 15	2A 500 10	2 5	0.8	1.5*	2A	3	250	3	420	6	5/6	5E				
BD633	TO-220	45	45	5	200 μA†	45	25 40	1A 25	2	0.6	1.3*	1A	3	250	3	420	6	5/6	4F				
BD634	TO-220	45	45	5	200 μA†	45	25 40	1A 25	2	0.6	1.3*	1A	3	250	3	420	6	5/6	5F				
BD635	TO-220	60	60	5	200 μA†	60	25 40	1A 25	2	0.6	1.3*	1A	3	250	3	420	6	5/6	4F				

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35539 D

Pro Electron Series

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PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE0} (V)		V _{BE0} (V)	I _{CS0} (mA)	I _{CB} (mA)	H _{FE} @ 1 kHz		I _C (mA)	V _{CE} (V)	V _{BE(SAT)} & V _{BE(ON)} (V)		I _C (mA)	C _{ob} (pF)	f _T (MHz)	I _C (mA)	t _{off} (ns)	NF (dB)	Test Conditions	Process No.
		Min	Max				Min	Max			Min	Max								
BD636	TO-220	60	60	5	200 μA†	60	25	40	1A	2	0.6	1.3*	1A	30	3	250	420	6	5/6	5F
BD637	TO-220	100	80	5	200 μA†	100	25	40	1A	2	0.6	1.3*	1A	30	3	250	420	6	5/6	4F
BD638	TO-220	100	80	5	200 μA†	100	25	40	1A	2	0.6	1.3	1A	30	3	250	420	6	5/6	5F
BD675	TO-126		45		200 μA	45	750		1.5A	3	2.5	2.5*	1.5A		1	1.5A				4J
BD675A	TO-126		45		200 μA	45	750		2A	3	2.8	2.5*	2A		1	1.5A				4J
BD676	TO-126		45		200 μA	45	750		1.5A	3V	2.5	2.5*	1.5A		1	1.5A				5J
BD676A	TO-126		45		200 μA	45	750		2A	3V	2.5	2.5*	2A		1	1.5A				5J
BD677	TO-126		60		200 μA	60	750		1.5A	3V	2.5	2.5*	1.5A		1	1.5A				4J
BD677A	TO-126		60		200 μA	60	750		2A	3V	2.8	2.5*	2A		1	1.5A				4J
BD678	TO-126		60		200 μA	60	750		1.5A	3V	2.5	2.5*	1.5A		1	1.5A				5J
BD678A	TO-126		60		200 μA	60	750		2A	3V	2.8	2.5*	2A		1	1.5A				5J
BD679	TO-126		80		200 μA	80	750		1.5A	3V	2.5	2.5*	1.5A		1	1.5A				4J
BD679A	TO-126		80		200 μA	80	750		2A	3V	2.8	2.5*	2A		1	1.5A				4J
BD680	TO-126		80		200 μA	80	750		1.5A	3V	2.5	2.5*	1.5A		1	1.5A				5J
BD680A	TO-126		80		200 μA	80	750		2A	3V	2.8	2.5*	2A		1	1.5A				5J
BD681	TO-126		100		200 μA	100	750		1.5A	3V	2.5	2.5*	1.5A		1	1.5A				4J
BD682	TO-126		100		200 μA	100	750		1.5A	3V	2.5	2.5*	1.5A		1	1.5A				5J
BD733	TO-220	25	25	5	200 μA†	25	50	40	2A	1	0.6	1.1*	2A		1	1.5A				4F
BD734	TO-220	25	25	5	200 μA†	25	50	40	2A	1	0.6	1.1*	2A		1	1.5A				5E
BD735	TO-220	35	35	5	200 μA†	35	40	40	2A	4	0.6	1.1*	2A		1	1.5A				4F
BD736	TO-220	35	35	5	200 μA†	35	40	40	2A	4	0.6	1.1*	2A		1	1.5A				5E
BD737	TO-220	45	45	5	200 μA†	45	40	40	2A	4	0.8	1.1*	2A		1	1.5A				4F
BD738	TO-220	45	45	5	200 μA†	45	40	40	2A	4	0.8	1.1*	2A		1	1.5A				5E
BD795	TO-220		45		100	45	40	40	1A	2	1.0	1.6*	3A	3	3	250				4E
BD796	TO-220		45		100	45	40	40	1A	2	1.0	1.6*	2A	3	3	250				5E
BD797	TO-220		60		100 μA	60	40	40	1A	2	1.0	1.6*	3A	3	3	250				4E

6501130 NATL SEMICOND, (DISCRETE)

28C 35540

T-33-01

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} [*] (V) Min	V _{CE0} [*] (V) Max	V _{BE0} (V) Min	V _{BE0} (V) Max	I _{CB0} [*] (mA) Max	I _{CB0} [*] (mA) Min	HFE I _{FE} 1 kHz [*] Min	HFE I _{FE} 1 kHz [*] Max	I _C & V _{CE} (mA) & (V)	V _{CE(SAT)} (V) Max	V _{BE(SAT)} (V) Min	V _{BE(SAT)} (V) Max	I _C (mA) Max	I _C (mA) Min	C _{ob} (pF) Max	f _T (MHz) Min	f _T (MHz) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BD798	TO-220	60	100	60	100	100	100	40	25	1A 2 3A 2	1.0	1.6*	3A	250	250		3					5E
BD799	TO-220	80	100	80	100	100	100	30	15	1A 2 3A 2	1.0	1.6*	3A	250	250		3					4E
BD800	TO-220	80	100	80	100	100	100	30	15	1A 2 3A 2	1.0	1.6*	3A	250	250		3					5E
BD801	TO-220	100	100	100	100	100	100	30	15	1A 2 3A 2	1.0	1.6*	3A	250	250		3					4E
BD802	TO-220	100	100	100	100	100	100	30	15	1A 2 3A 2	1.0	1.6*	3A	250	250		3					5E
BD895	TO-220	45	200	45	200	200	200	750	45	3A 3	2.5*	2.5*	3A	3A	3A		1					4K
BD895A	TO-220	45	200	45	200	200	200	750	45	4A 3	2.5*	2.5*	4A	3A	3A		1					4K
BD896	TO-220	45	200	45	200	200	200	750	45	3A 3	2.5*	2.5*	3A	3A	3A		1					5K
BD896A	TO-220	45	200	45	200	200	200	750	45	4A 3	2.5*	2.5*	4A	3A	3A		1					5K
BD897	TO-220	60	200	60	200	200	200	750	45	3A 3	2.5*	2.5*	3A	3A	3A		1					4K
BD897A	TO-220	60	200	60	200	200	200	750	45	4A 3	2.5*	2.5*	4A	3A	3A		1					4K
BD898	TO-220	60	200	60	200	200	200	750	45	3A 3	2.5*	2.5*	3A	3A	3A		1					5K
BD898A	TO-220	60	200	60	200	200	200	750	45	4A 3	2.5*	2.5*	4A	3A	3A		1					5K
BD899	TO-220	80	200	80	200	200	200	750	45	3A 3	2.5*	2.5*	3A	3A	3A		1					4K
BD899A	TO-220	80	200	80	200	200	200	750	45	4A 3	2.5*	2.5*	4A	3A	3A		1					4K
BD900	TO-220	80	200	80	200	200	200	750	45	3A 3	2.5*	2.5*	3A	3A	3A		1					5K
BD900A	TO-220	80	200	80	200	200	200	750	45	4A 3	2.5*	2.5*	4A	3A	3A		1					5K
BD901	TO-220	100	200	100	200	200	200	750	45	3A 3	2.5*	2.5*	3A	3A	3A		1					4K
BD901A	TO-220	100	200	100	200	200	200	750	45	4A 3	2.5*	2.5*	4A	3A	3A		1					4K
BDX33	TO-220	45	1 mA	45	1 mA	1 mA	1 mA	750	45	4A 3	2.5*	2.5*	4A	1A	1A		20					4K
BDX33A	TO-220	60	1 mA	60	1 mA	1 mA	1 mA	750	45	4A 3	2.5*	2.5*	4A	1A	1A		20					4K
BDX33B	TO-220	80	1 mA	80	1 mA	1 mA	1 mA	750	45	3A 3	2.5*	2.5*	3A	1A	1A		20					4K
BDX33C	TO-220	100	1 mA	100	1 mA	1 mA	1 mA	750	45	3A 3	2.5*	2.5*	3A	1A	1A		20					4K
BDX33D	TO-220	120	1 mA	120	1 mA	1 mA	1 mA	750	45	3A 3	2.5*	2.5*	3A	1A	1A		20					4K
BDX34	TO-220	45	1 mA	45	1 mA	1 mA	1 mA	750	45	4A 3	2.5*	2.5*	4A	1A	1A		20					5K
BDX34A	TO-220	60	1 mA	60	1 mA	1 mA	1 mA	750	45	4A 3	2.5*	2.5*	4A	1A	1A		20					5K
BDX34B	TO-220	80	1 mA	80	1 mA	1 mA	1 mA	750	45	3A 3	2.5*	2.5*	3A	1A	1A		20					5K

TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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6501130 NATL SEMICOND, (DISCRETE)

28C 35542

D

PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} [*] (V) Min	V _{BE0} [*] (V) Min	I _{CB0} [*] (mA) Max	h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) (V) Min Max	V _{CE(SAT)} & V _{BE(ON)} [*] (V) (V) Max Min		I _C (mA) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
							V _{CE(SAT)} (V) Max	V _{BE(ON)} [*] (V) Min							
BF254	TO-92 (98)	20	5	100	20	1 10	0.65 0.74*	1	0.34				3.5	7	46
BF255	TO-92 (98)	20	5	100	36	1 10	0.65 0.74*	1	0.34				3.5	7	46
BF257	TO-39	100	5	50	25	30 10	1.0 0.65 0.74*	30	0.34				3.5	7	48
BF258	TO-39	250	5	50	25	30 10	1.0 0.65 0.74*	30	0.34				3.5	7	48
BF259	TO-39	300	5	50	25	30 10	1.0 0.65 0.74*	30	0.34				3.5	7	48
BF457	TO-126	100	5	50	25	30 10	1.0 0.65 0.74*	30	0.34				3.5	7	48
BF458	TO-126	250	5	50	25	30 10	1.0 0.65 0.74*	30	0.34				3.5	7	48
BF459	TO-126	300	5	50	25	30 10	1.0 0.65 0.74*	30	0.34				3.5	7	48
BFX13	TO-18	20	5	50	10	100 2	0.2 0.78 1	1	6	150	10		10	8	66
BFX29	TO-5	20	5	50	50	10 0.35	0.25 0.7 0.9 10	1	0.12	100	50	150		9	63
BFX30	TO-5	65	5	50	20	1 0.4	1.5 1.5 100	1	12			290		4	63
BFX37	TO-18	60	6	20†	100	10 5	0.4 1.3 150	50	6	40	0.5		3	1	62
BFX65	TO-18	45	6	10*	100	1 5	0.25 0.9 10	10	6.5				3	1	62

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TEST CONDITIONS:
 (1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

Pro Electron Series

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Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35543 D

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PRO ELECTRON SERIES (Continued)



Type No.	Case Style	V _{CE} [*] V _{CB} (V) Min	V _{CE} [*] (V) Min	V _{EB} [*] (V) Min	I _{CB} [*] (mA) Max	HFE h _{FE} 1 kHz [*] Min Max	I _C & V _{CE} (mA) & (V) Min Max	V _{CE(SAT)} (V) Max	V _{BE(SAT)} & V _{BE(ON)} [*] (V) Min Max	I _C (mA) Min Max	C _{ob} (pF) Max	f _T (MHz) Min Max	I _C (mA) Max	t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
BFX84	TO-39	45	45	6	500	15 20 30 20	1A 500 150 10	0.15 0.35 1.0 1.6	1.2 1.3 1.5 2.0	10 150 500 1A	12	50	50	360		9	14
BFX85	TO-39	45	45	6	50	15 30 70 50	1A 500 150 10	0.15 0.35 1.0 1.6	1.2 1.3 1.5 2.0	10 150 500 1A	12	50	50	360		9	14
BFX86	TO-39	45	45	6	50	15 30 70 50	1A 500 150 10	0.15 0.35 1.0 1.6	1.2 1.3 1.5 2.0	10 150 500 1A	12	50	50	360		9	14
BFX87	TO-5	45	50	6	50	25 40 40 40	500 150 10 1	0.4 0.35 1.0 1.6	1.3 1.3 1.5 2.0	150 30 500 1A	12	100	50	150		9	63
BFX88	TO-5	45	40	6	50	25 40 40 40	500 150 10 1	0.4 0.35 1.0 1.6	1.3 1.3 1.5 2.0	150 30 500 1A	12	100	50	150		9	63
BFY39	TO-18	45	25	5	50	35	400	1.0	1.0	10		150	10				23
BFY39-1	TO-18	45	25	5	50	35	110	1.0	1.0	10		150	10				23
BFY39-2	TO-18	45	25	5	50	100	200	1.0	1.0	10		150	10				23
BFY39-3	TO-18	45	25	5	50	180	400	1.0	1.0	10		150	10				23
BFY50	TO-18	80	35	6	500	20	10	0.1	1.2	10	12	60	50	360		9	14
BFY51	TO-39	60	30	6	500	30 40 25 15	10 150 10 1A	0.1	1.2	10	12	60	50	360		9	14
BFY52	TO-39	40	20	6	500	30 60 30 15	10 150 10 1A	0.1	1.2	10	12	60	50	360		9	14
BFY56	TO-39	80	45	5	50	15 20 30	1 500 150	0.3 1.2	1.5 2.5	150 1A	25	40	50				14

6501130 NATL SEMICOND, (DISCRETE)

28C 35544

D



PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} [*] (V)		V _{CE0} (V) Min	V _{BE0} (V) Min	I _{CB0} [*] (mA) Max	HFE		I _C & V _{CE} (mA) (V)	V _{CE(SAT)} & V _{BE(ON)} [*] (V) (V)		I _C (mA)		C _{ob} (pF) Max	f _T (MHz)		t _{off} (ns) Max	NF (dB) Max	Test Conditions	Process No.
		Min	Max				Min	Max		Min	Max	Min	Max		Min	Max				
BFY72	TO-39	50	28	5	20	40*	15	20	0.1	10	0.25	1.2	150	8	50	50				19
BFY76	TO-18	45	45	6	30	20	30	200	0.01	5	0.35	1.6	500	6						
BSX21	TO-18		80			500	20	4	3		0.9	4			60	4				07
BSX45-6	TO-39	80*	40	7	60	10*	40	100	100	1	1.0	2.0	1A	20	60	50				14
BSX45-10	TO-39	80*	40	7	60	10*	63	160	100	1	1.0	2.0	1A	20	60	50				14
BSX45-16	TO-39	80*	40	7	60	10*	100	250	100	1	1.0	2.0	1A	20	60	50				14
BSX46-6	TO-39	100*	60	7	60	10*	40	100	100	1	1.0	2.0	1A	25	60	50				12
BSX46-10	TO-39	100*	60	7	60	10*	63	160	100	1	1.0	2.0	1A	25	60	50				12
BSX46-16	TO-39	100*	60	7	60	10*	100	250	100	1	1.0	2.0	1A	25	60	50				12
BSX48	TO-18	50	25	5	50	120	17	100	1	1.5	1.5	500	6	250	30					19
BSX88	TO-18	40	15	5	20	25	15	0.5	1	0.5	0.72	0.8	10	6	300	10				21
BSY38	TO-18	20	12	5	100	20	30	60	0.35	0.25	0.7	0.85	10	5	200	10	45		16	21
BSY39	TO-18	20	12	5	100	20	15	45	100	1	0.6	1.5	100	5	200	10	45		16	21
BSY51	TO-18	60	35	5	100	30	40	120	150	10	1.0	1.3	150	9	130	50				19
BSY62	TO-18	60	25	5	100	30	100	300	150	10	1.0	1.3	150	9	130	50				19
BSY63	TO-18	75	30	7	10	60	20	0.1	10	0.6	1.3	150	9	150	50					19

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TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 10 mA, V_{CE} = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

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Pro Electron Series

Pro Electron Series

6501130 NATL SEMICOND, (DISCRETE)

28C 35545 D

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PRO ELECTRON SERIES (Continued)

Type No.	Case Style	V _{CE0} [*] (V)		V _{BE0} (V)		I _{CB0} (mA)		HFE		I _C & V _{CE} (V)		V _{CE(SAT)} & V _{BE(ON)} [*] (V)		C _{ob} (pF)		f _T (MHz)		t _{off} (ns)	NF (dB)	Test Conditions	Process No.
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max				
BSY54	TO-18	75	30	7	60	10	10	35	75	10	10	0.6	1.3	9	150	50	150	50			19
BSY95A	TO-18	20	15	5	16	50	10	30	200	10	0.35	0.67	0.87	6	10	200	10				21

TEST CONDITIONS:

(1) I_C = 200 μA, V_{CE} = 5V, f = 1 kHz. (2) I_C = 100 mA, V_{CE} = 20V, I_B¹ = I_B² = 5 mA. (3) I_C = 200 μA, V_{CE} = 2V, f = 1 kHz. (4) I_C = 100 mA, V_{CE} = 10V, I_B¹ = I_B² = 10 mA. (5) I_C = 3V, I_B¹ = I_B² = 1 mA. (6) I_C = 100 μA, V_{CE} = 5V, f = 1 kHz. (7) I_C = 1 mA, V_{CE} = 10V, f = 200 kHz. (8) I_C = 1 mA, V_{CE} = 5V, f = 1 kHz. (9) I_C = 150 mA, V_{CE} = 6V, I_B¹ = I_B² = 15 mA. (10) I_C = 10 μA, V_{CE} = 5V, f = WB.

